

APPLICATION DATA SHEET

Electronic Version v14

Stylesheet Version v14.0

Title of Invention	[LOW TEMPERATURE POLYSILICON THIN FILM TRANSISTOR AND METHOD OF MANUFACTURING THE SAME]
Application Type :	regular, utility
Attorney Docket Number :	10958-US-PA
Correspondence address:	
Customer Number:	31561
	
Priority Data:	
Doc.No: 92108769; Country -TW ; Date: 2003-04-16 us-priority-claimed	
Inventors Information:	
<u>Inventor 1:</u>	
Applicant Authority Type:	Inventor
Citizenship:	TW
Name prefix:	Mr.
Given Name:	Chia-Tien
Family Name:	Peng
Residence:	
City of Residence:	Hsinchu Hsien
Country of Residence:	TW
Address-1 of Mailing Address:	No. 10, Alley 9, Lane 239, Paiti St., Chupei City
Address-2 of Mailing Address:	
City of Mailing Address:	Hsinchu Hsien
State of Mailing Address:	
Postal Code of Mailing Address:	
Country of Mailing Address:	TW
Phone:	
Fax:	
E-mail:	
<u>Inventor 2:</u>	
Applicant Authority Type:	Inventor

Citizenship:	TW
Name prefix:	Mr.
Given Name:	Ming-Wei
Family Name:	Sun
Residence:	
City of Residence:	Kaohsiung
Country of Residence:	TW
Address-1 of Mailing Address:	9Fl.-3, No. 342, Chungde Rd., Tzuoying Chiu
Address-2 of Mailing Address:	
City of Mailing Address:	Kaohsiung
State of Mailing Address:	
Postal Code of Mailing Address:	813
Country of Mailing Address:	TW
Phone:	
Fax:	
E-mail:	

Attorney Information:

practitioner(s) at Customer Number:

31561



as our attorney(s) or agent(s) to prosecute the application identified above, and to transact all business in the United States Patent and Trademark Office connected therewith.